



ON Semiconductor

DN06040/DDesign Note – DN**06040/D-#**

Universal Input, 20 W, LED Ballast

Device	Application	Input Voltage	Output Power	Topology	I/O Isolation
NCP1351	Solid State Lighting	85 – 265 Vac	20 W	Flyback	Yes

Other Specifications

	Output 1			
Maximum Output Voltage	33 V			
Ripple	Not Given			
Nominal Current	700 mA			

PFC (Yes/No)	No
Target Efficiency	80 % at nominal load
Max Size	125 x 37 x 35 mm
Operating Temp Range	0 to +70°C
Cooling Method/Supply Orientation	Convection
Signal Level Control	No

Other Requirements	
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Circuit Description

The NCP1351 controller provides for a low cost, variable frequency, flyback converter. It incorporates a very low quiescent current allowing for high value resistors to be used as a start-up circuit direct from the HV rail.

The design comprises an input filter, bridge rectifier (using low cost 1N4007 diodes), bulk capacitors and line inductor in π -filter arrangement, the power stage, rectifier diode and smoothing capacitors. Feedback is CVCC, constant current drive for the LED's with a constant voltage in the event of an open circuit output.

In order not to need PFC the input power is capped at 25 W, so assuming 80% efficiency the maximum output power is ~20 W.

In cooperation with

Key Features

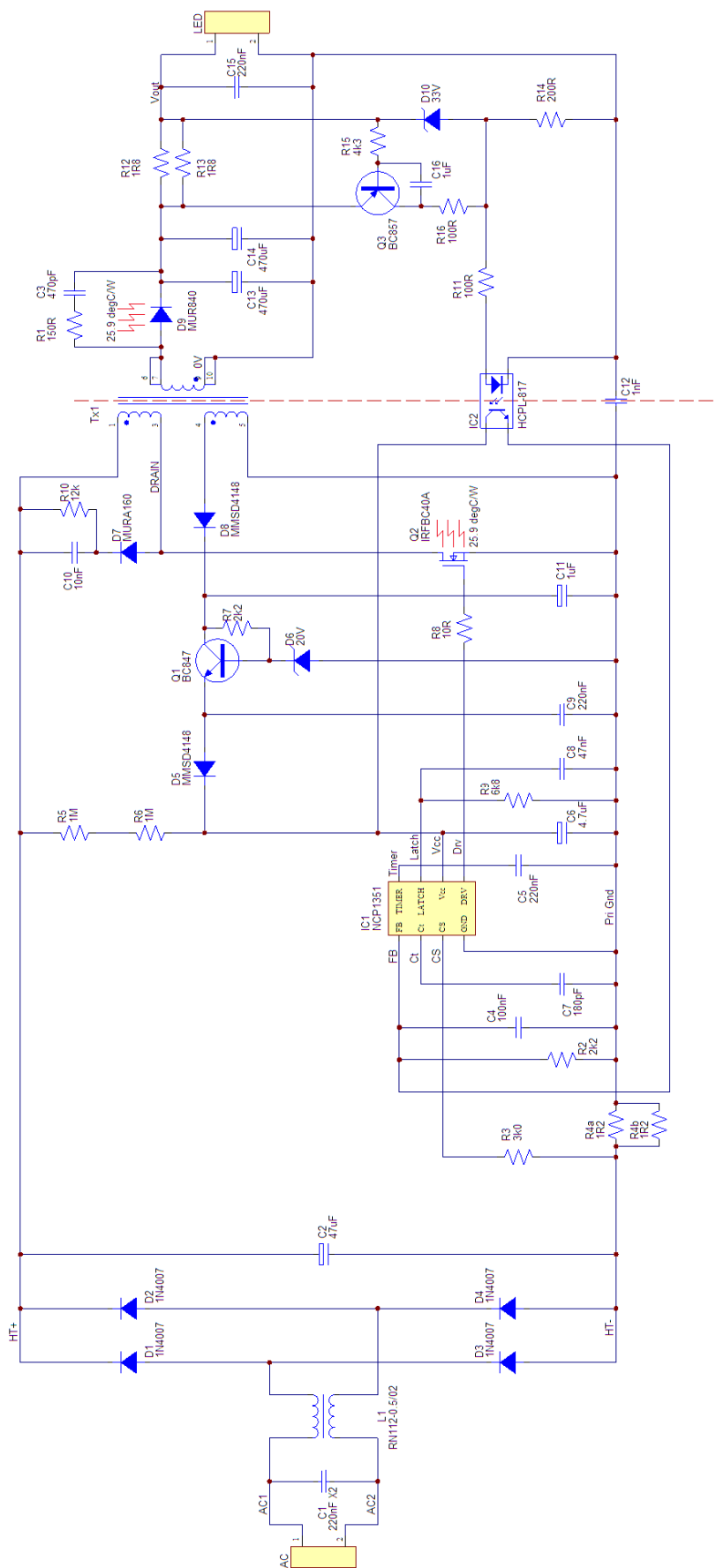
- Wide input voltage range – 85 Vac to 265 Vac
- Small size, and low cost
- Good line regulation
- High efficiency
- Overload and short circuit protection.

Number of LED's in series	LED Current			
	350 mA	700 mA	1 A	1.5 A
LUXEON® I	11		#NOTE1	
LUXEON® III	10	6	4	#NOTE1
LUXEON® V	5	3	#NOTE1	
LUXEON® K2	11	6	4	2
LUXEON® K2 with TFFC	#NOTE2		4	2
LUXEON® Rebel	11	6	4	#NOTE1
V _Z (D10)	47 V	33 V	22 V	12 V
R12 & R13	3R6	1R8	1R2	0R8

#NOTE1 Out of LED specification.

#NOTE2 Recommended for use above 1 A.

DN06040/D Schematic



LED Current

The light output of an LED is determined by the forward current so the control loop will be constant current, with a simple Zener to limit the maximum output voltage.

For a white LUXEON® K2 the VI characteristics are:

I_F	V_F
350 mA	3.42 V
700 mA	3.60 V
1000 mA	3.72 V
1500 mA	3.85 V

Driving eight LED's at 700mA thus gives an output power of 20.2 W at 28.8 V.

Inductor selection

In a flyback converter the inductance required in the transformer primary is dependant on the mode of operation and the output power. Discontinuous operation requires lower inductance but results in higher peak to average current waveforms, and thus higher losses. For low power designs, such as this ballast, the inductance is designed to be just continuous (or just discontinuous) under worst case conditions, that is minimum line and maximum load.

The specification for this ballast is as follows:

- Universal input – 85 Vac to 265 Vac
- 25 W maximum input power – PFC limit
- Assuming 80% efficiency – 20 W output power
- 700 mA output current
- 100 kHz operation at full load

This gives us a minimum DC input voltage of 120 V, there will be some sag on the DC bulk capacitors so an allowance will be made for this by using 80 V as the minimum input voltage, including MOSFET drop etc.

First we need to calculate the turn's ratio, this is set by the MOSFET drain rating, line voltage and reflected secondary voltage. Since this is a constant current circuit we are designing, with a varying output voltage, we need the maximum output voltage.

- $V_{IN(max)}$ is the maximum rectified input = 375 V.
- $V_{IN(min)}$ is the minimum rectified input = 80 V.
- V_{OUT} is 35 V (20 W @ 700 mA is 29 V plus a margin for safety).

With a 600 V MOSFET and derating of 80%, our maximum allowable drain voltage is:

$$V_{D(max)} = 600 \times 0.8 = 480 \text{ V} \quad \text{..... (Eq.3)}$$

And thus headroom, V_{CLAMP} for the reflected secondary voltage and leakage spike of:

$$V_{CLAMP} = V_{D(max)} - V_{IN(max)} = 480 - 375 \\ = 105 \text{ V} \quad \text{..... (Eq.4)}$$

The output current is sensed by a series resistance, once the voltage drop across this reaches the base-emitter threshold of the PNP transistor current flows in the opto-coupler diode and thus in the FB pin of the NCP101x.

The LED current is thus set by:

$$I_{LED} = \frac{0.6V}{R_{SENSE}} \quad \text{..... (Eq.1)}$$

Total sense resistor power dissipation is:

$$P_D = I_{LED} \times 0.6V \quad \text{..... (Eq.2)}$$

So for 700 mA we need a 0.9 Ω sense resistor capable of dissipating 420 mW, two 330 mW surface mount resistors, 1.8 Ω each in parallel, are used.

Good results are obtained if we set V_{CLAMP} , at ~150% of the reflected secondary:

$$k_C = \frac{V_{CLAMP} \times N}{(V_{OUT} + V_f)} = 1.5 \quad \text{..... (Eq.5)}$$

- $V_f = 0.7 \text{ V}$ as we will need a high voltage diode.

Re-arranging for N:

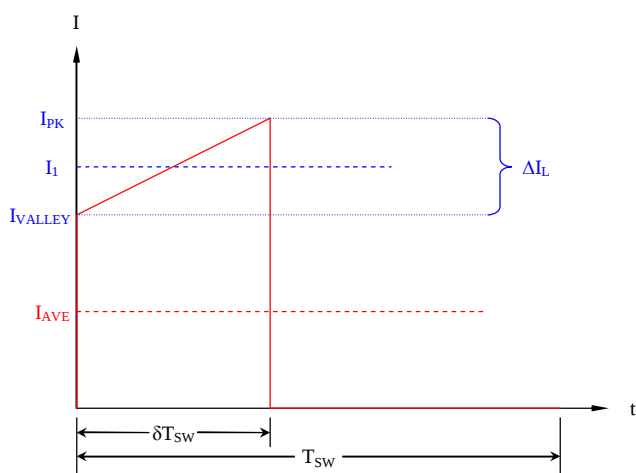
$$N = \frac{N_s}{N_p} = \frac{1.5 \times (35 + 0.7)}{105} \quad \text{..... (Eq.6)} \\ = 0.51$$

We will use a ratio of 0.5 or 2:1, this will give a good transformer construction.

We can now calculate the maximum duty cycle running in CCM:

$$\delta_{MAX} = \frac{V_{OUT}}{V_{OUT} + V_{IN(min)}N} = \frac{(35 + 0.7)}{(35 + 0.7) + 80 \times 0.5} \\ = 0.47 \quad \text{..... (Eq.7)}$$

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Looking at the waveform of the current flowing in the primary of the inductor (above) if we define a term k equal to;

$$k = \frac{\Delta I_L}{I_1} \dots\dots\dots (\text{Eq.8})$$

And use the equation:

$$L = \frac{(V_{IN(\min)} \delta_{MAX})^2}{f_{SW} k P_{IN}} \dots\dots\dots (\text{Eq.9})$$

Then we can determine the inductance we require.

If $k = 2$ then we are in boundary conduction mode as the ripple current equals twice the average pulse current, so setting k to 2:

$$L = \frac{(80 \times 0.47)^2}{100 \times 10^3 \times 2.0 \times 25} = 283 \mu H \dots\dots\dots (\text{Eq.10})$$

Thus we can now find the primary ripple current assuming operation in boundary conduction mode:

$$\begin{aligned} \Delta I_L &= \frac{V_{IN(\min)} T_{ON}}{L} = \frac{V_{IN(\min)} \delta_{max}}{L f_{SW}} \dots\dots\dots (\text{Eq.11}) \\ &= \frac{80 \times 0.47}{283 \times 10^{-6} \times 100 \times 10^3} = 1.32 \text{ A} \end{aligned}$$

The average input current, I_{AVE} , is:

$$I_{AVE} = \frac{P_{IN}}{V_{IN(\min)}} = \frac{25}{80} = 313 \text{ mA} \dots\dots\dots (\text{Eq.12})$$

The average pulse current, I_1 , is:

$$I_1 = \frac{I_{AVE}}{\delta_{max}} = \frac{0.313}{0.47} = 662 \text{ mA} \dots\dots\dots (\text{Eq.13})$$

Demonstrating that ΔI_L does equal twice I_1 and that the peak primary current is 1.32 A.

We can calculate the RMS current in the MOSFET and sense resistor for dissipation purposes. For a stepped-sawtooth waveform of this type the equation is:

$$I_{RMS} = I_1 \sqrt{\delta} \sqrt{1 + \frac{1}{3} \left(\frac{\Delta I_L}{2 I_1} \right)^2} \dots\dots\dots (\text{Eq.14})$$

Thus:

$$\begin{aligned} I_{RMS} &= 0.665 \times \sqrt{0.47} \times \sqrt{1 + \frac{1}{3} \left(\frac{1.32}{2 \times 0.665} \right)^2} \\ &= 526 \text{ mA} \dots\dots\dots (\text{Eq.15}) \end{aligned}$$

We can also determine the current sense resistor, allowing for a drop across the resistor of 0.8 V:

$$R_{SENSE} = \frac{V_{DROP}}{I_{PK}} = \frac{0.8}{1.32} = 0.61 \Omega \dots\dots\dots (\text{Eq.16})$$

The total power dissipation is:

$$\begin{aligned} P_{D(sense)} &= I_{RMS}^2 R_{SENSE} = 0.526^2 \times 0.61 \\ &\cong 170 \text{ mW} \dots\dots\dots (\text{Eq.17}) \end{aligned}$$

Two 1.2 Ω resistors in parallel will be used as sub 1 Ω resistors typically cost more.

The threshold voltage for the current sense is set by an offset resistor; this has a bias current of 270 μA in it so we can determine the resistor value:

$$R_{OFFSET} = \frac{V_{SENSE}}{I_{BIAS}} = \frac{0.8}{270 \times 10^{-6}} \cong 3.0 \text{ k}\Omega \dots\dots (\text{Eq.18})$$

Rectifier snubber

Testing demonstrated the need for snubbing on the rectifier as there was a large amount of ringing present after the rectifier turns off.

The snubber consists of a resistor and capacitor in series, and knowing the junction capacitance and ringing frequency we can determine the necessary values:

$$R_s = \sqrt{\frac{L}{C_j}} \dots\dots\dots (\text{Eq.19})$$

$$C_s = \frac{2\pi\sqrt{LC_j}}{R_s} \dots\dots\dots (\text{Eq.20})$$

Knowing that:

$$f = \frac{1}{2\pi\sqrt{LC_j}} \dots\dots\dots (\text{Eq.21})$$

We can determine L , the stray inductance which then allows us to calculate the necessary snubber resistor.

- $f = 14.5 \text{ MHz}$ (measured on oscilloscope)
- $C_j = 80 \text{ pF}$ (datasheet figure for MUR840 at 62 V)

$$L = \frac{1}{4C_j(\pi f)^2} = \frac{1}{4 \times 80 \times 10^{-12} \times (\pi \times 14.5 \times 10^6)^2} = 1.51 \mu\text{H} \dots\dots\dots (\text{Eq.22})$$

$$R_s = \sqrt{\frac{1.51 \times 10^{-6}}{80 \times 10^{-12}}} = 137 \Omega \dots\dots\dots (\text{Eq.23})$$

$$C_s = \frac{2 \times \pi \times \sqrt{1.51 \times 10^{-6} \times 80 \times 10^{-12}}}{137} = 504 \text{ pF} \dots\dots\dots (\text{Eq.24})$$

The nearest standard values are 470 pF and 140 Ω , inserting these into the circuit eliminated the ringing due to the rectifier.

Auxiliary winding

Normally in a flyback converter the auxiliary winding would be in the form of a flyback winding, i.e. in phase with the output winding, and thus provide a semi-regulated voltage to supply the controller. As this ballast is current controlled and the output voltage can vary over a considerable range depending on the number of LED's connected, a forward phased winding is used. The auxiliary will therefore vary with line rather than output voltage. Since neither option could supply sufficient volts at low input/output voltage whilst still staying below the maximum V_{CC} figure of 28 V, a voltage regulator is used formed by Q1 and D6. Below ~20 V the regulator does nothing other than act as a small volt drop, however as the voltage rises it clamps the voltage to around 20.7 V, since the current is very low into the V_{CC} pin there is very little loss.

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MAGNETICS DESIGN DATA SHEET

Project / Customer: ON Semiconductor/Future Lighting Solution
Part Description: 25 W Transformer
Schematic ID: -
Core Type: EE25
Core Gap: Gap for 250 μ H
Inductance: 250 μ H
Bobbin Type: NIC 10-pin vertical

Windings (in order):

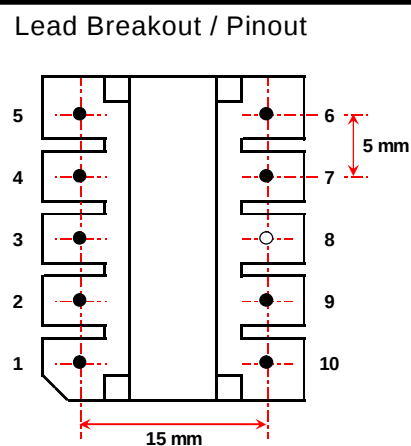
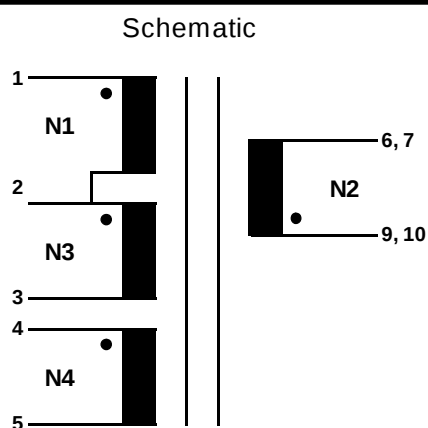
Winding # / type	Turns / Material / Gauge / Insulation Data
N1, Primary	Start on pin 1 and wind 20 turns, of 0.28 mm triple insulated wire (e.g. Tex-E), in one neat layer across the entire bobbin width. Finish on pin 2.
N2, Secondary	Start on pins 9&10 and wind 20 turns, of 0.8 mm Grade II ECW, distributed evenly across the entire bobbin width. Finish on pins 6&7.
N3, Primary	Start on pin 2 and wind 20 turns, of 0.28 mm triple insulated wire (e.g. Tex-E), in one neat layer across the entire bobbin width. Finish on pin 3.
N4, Primary (Aux)	Start on pin 4 and wind 5 turns, of 0.28 mm triple insulated wire, in one neat layer spread evenly across the entire bobbin width. Finish on pin 5.

Sleeving and insulation between primary and secondary as required to meet requirements of double insulation.

Primary leakage inductance (pins 6&7 and 9&10 shorted together) to be < 6 μ H

NIC part number: NLT282224W3P4020S5P10F

Hipot: 3 kV between pins 1, 2, 3, 4 & 5 and pins 6, 7, 8, 9 & 10 for 60 seconds.

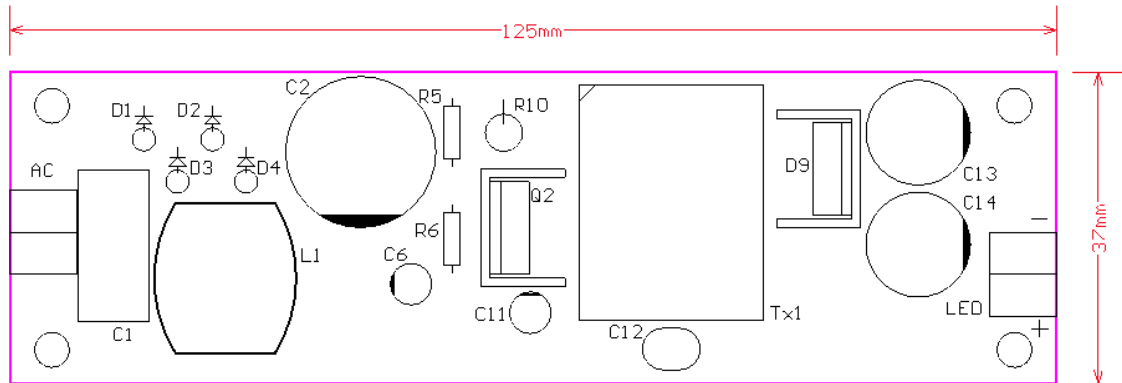


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Bill of Materials

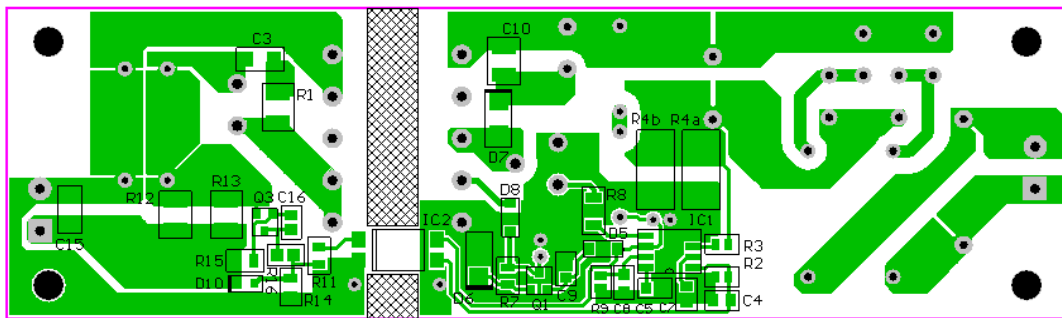
Ref	Part Type / Value	Comment	Footprint	Description	Manufacturer	Part Number
C1	220nF X2	275VAC	18X10mm, 15mm pitch	X-class EMI suppression capacitor	NIC	NPX224M275VX2MTBF
C2	47uF	400V	Ø16mm, 7.5mm pitch	General purpose high voltage electrolytic	NIC	NREH470M40016X31F
C3	470pF	100V X7R	1206	Ceramic chip capacitor	NIC	NMC1206X7R471K100TPRF
C4	100nF	50V X7R	0603	Ceramic chip capacitor	NIC	NMC0603X7R104K50TRPF
C5	220nF	50V X7R	0603	Ceramic chip capacitor	NIC	NMC0603X7R224K50TRPF
C6	4.7uF	35V	Ø5mm, 2mm pitch	General purpose low voltage electrolytic	NIC	NRWA4R7M50V5X11TRF
C7	180pF	50V NP0	0603	Ceramic chip capacitor	NIC	NMC0603NP0181J50TRPF
C8	47nF	50V X7R	0603	Ceramic chip capacitor	NIC	NMC0603X7R473K50TRPF
C9	220nF	50V X7R	0603	Ceramic chip capacitor	NIC	NMC0805X7R224K50
C10	10nF	1kV NP0	1210	Ceramic chip capacitor	NIC	NMC-H1210NP0221K1KVTRPF
C11	1uF	50V	Ø5mm, 2mm pitch	General purpose low voltage electrolytic	NIC	NRWA1R0M50V5X11TRF
C12	1nF	Y1	Radial, pitch 10mm	Ceramic Y-class capacitor	Murata	DE1E3KX102MN4AL01
C13	470uF	16V	Ø12.5mm, 5mm pitch	Miniature low impedance electrolytic	NIC	NRSZ471M63V12.5X25F
C14	470uF	16V	Ø12.5mm, 5mm pitch	Miniature low impedance electrolytic	NIC	NRSZ471M63V12.5X25F
C15	220nF	100V X7R	1206	Ceramic chip capacitor	NIC	NMC1206X7R224K100
C16	1uF	50V	1206	Ceramic chip capacitor	NIC	NMC1206X7R105Z50TRPF
D1	1N4007	1A, 1000V	Axial	Axial Lead, Standard Recovery	ON Semiconductor	1N4007RLG
D2	1N4007	1A, 1000V	Axial	Axial Lead, Standard Recovery	ON Semiconductor	1N4007RLG
D3	1N4007	1A, 1000V	Axial	Axial Lead, Standard Recovery	ON Semiconductor	1N4007RLG
D4	1N4007	1A, 1000V	Axial	Axial Lead, Standard Recovery	ON Semiconductor	1N4007RLG
D5	MMSD4148	200mA, 100V	SOD-123	Switching diode	ON Semiconductor	MMSD4148T1G
D6	20V	1.5W	SMA	Zener Diode	ON Semiconductor	1SMA5932BT3G
D7	MURA160	1A, 600V	SMA	Ultrafast rectifier	ON Semiconductor	MURA160T3G
D8	MMSD4148	200mA, 100V	SOD-123	Switching diode	ON Semiconductor	MMSD4148T1G
D9	MUR840	8A, 400V	DO-220	Ultrafast Power Rectifier	ON Semiconductor	MUR840G
D10	33V	5%, 200mW	SOD323	Zener diode	ON Semiconductor	MM3Z33VT1G
IC1	NCP1351	-	SOIC8	Variable Off-Time PWM Controller	ON Semiconductor	NCP1351BDR2G
IC2	HCPL-817	Wide pitch	HCPL-817-300E	Opto-coupler HCPL-817	Agilent	HCPL-817-W0AE
L1	RN112-0.5/02	-	RN112	Common Mode Choke	Schaffner	RN112-0.5/02
AC	2-Way	5mm pitch	-	Screw Terminal	-	-
LED	2-Way	5mm pitch	-	Screw Terminal	-	-
M1	25.9°C/W	-	-	Heatsink	Aavid	577102B00000G
M2	25.9°C/W	-	-	Heatsink	Aavid	577102B00000G
Q1	BC847	45V	SOT-23	General purpose NPN	ON Semiconductor	BC847ALT1G
Q2	IRFBC40A	600V	TO-220	MOSFET	IR	IRFBC40A
Q3	BC857	-45V	SOT-23	General purpose PNP	ON Semiconductor	BC857ALT1G
R1	150R	0.33W	1210	Resistor thick film NRC	NIC	NRC25J151TRF
R2	2k2	0.1W	0603	Resistor thick film NRC	NIC	NRC06J222TRF
R3	3k0	0.1W	0603	Resistor thick film NRC	NIC	NRC06J302TRF
R4a	1R2	1W	2512	Resistor thick film NRC	NIC	NRC100J1R2TRF
R4b	1R2	1W	2512	Resistor thick film NRC	NIC	NRC100J1R2TRF
R5	1M	1W	Axial	Carbon film resistor	NIC	NCF100J105TRF
R6	1M	1W	Axial	Carbon film resistor	NIC	NCF100J105TRF
R7	2k2	0.125W	0805	Resistor thick film NRC	NIC	NRC10J222TRF
R8	10R	0.25W	1206	Resistor thick film NRC	NIC	NRC12J100TRF
R9	6k8	0.1W	0603	Resistor thick film NRC	NIC	NRC06J682TRF
R10	12k	2W	Axial	Carbon film resistor	NIC	NRC200J123TRF
R11	100R	0.125W	0805	Resistor thick film NRC	NIC	NRC10J101TR
R12	1R8	0.33W	1210	Resistor thick film NRC	NIC	NRC25J1R8TRF
R13	1R8	0.33W	1210	Resistor thick film NRC	NIC	NRC25J1R8TRF
R14	200R	0.125W	0805	Resistor thick film NRC	NIC	NRC10J201TRF
R15	4k3	0.125W	0805	Resistor thick film NRC	NIC	NRC10J432TRF
R16	100R	0.125W	0805	Resistor thick film NRC	NIC	NRC10J101TRF
Tx1	FUTURE 24W LED TRANSFORMER	-	NIC 10 pin vertical	24W Flyback transformer	NIC	NLT282224W3P4020S5P10F

All parts can be ordered from Future Electronics

DN06040/D
Component Locations



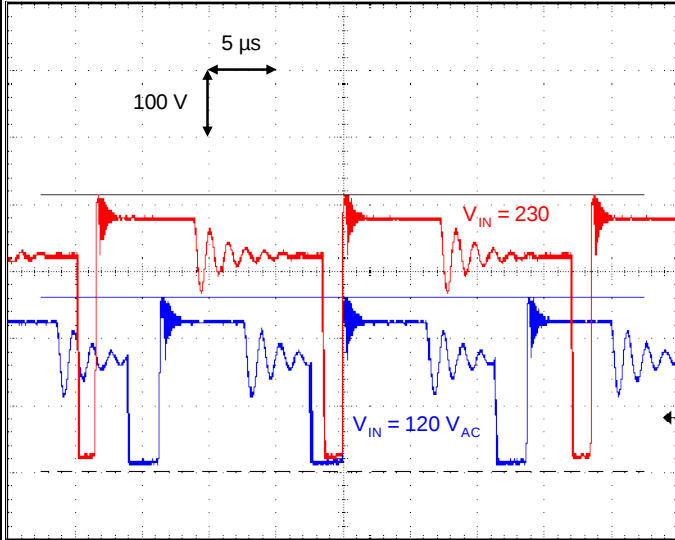
Top view.



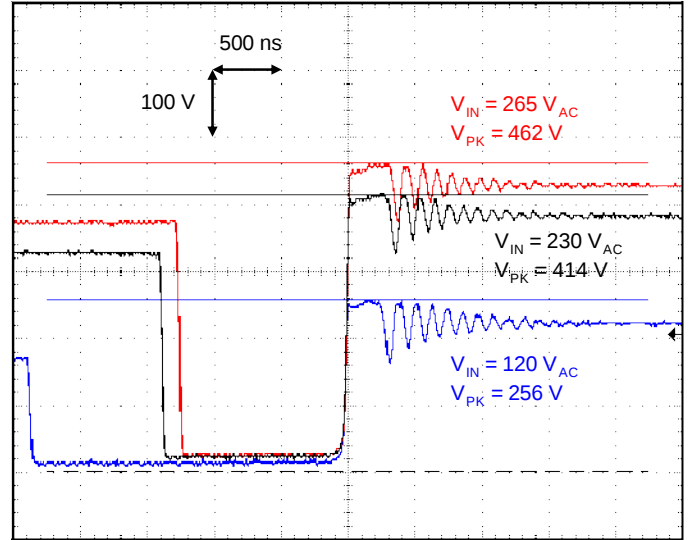
Bottom view.

DN06040/D
PCB Tracks

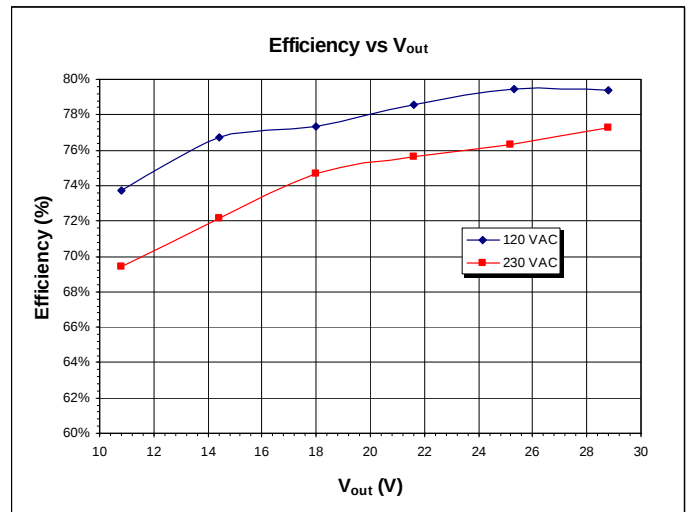
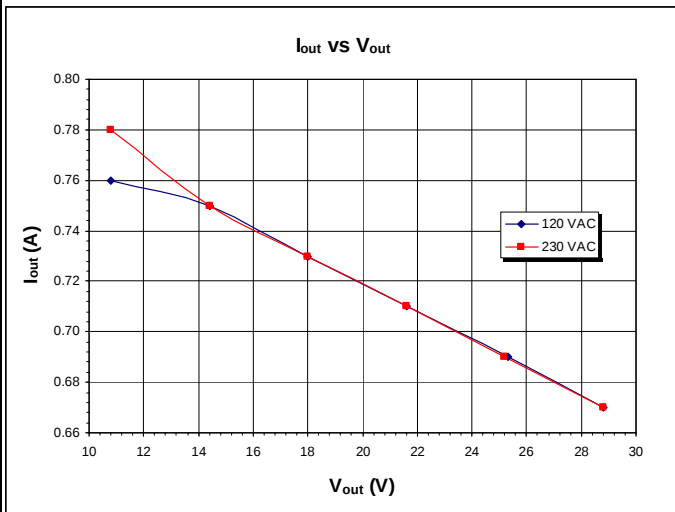
Results



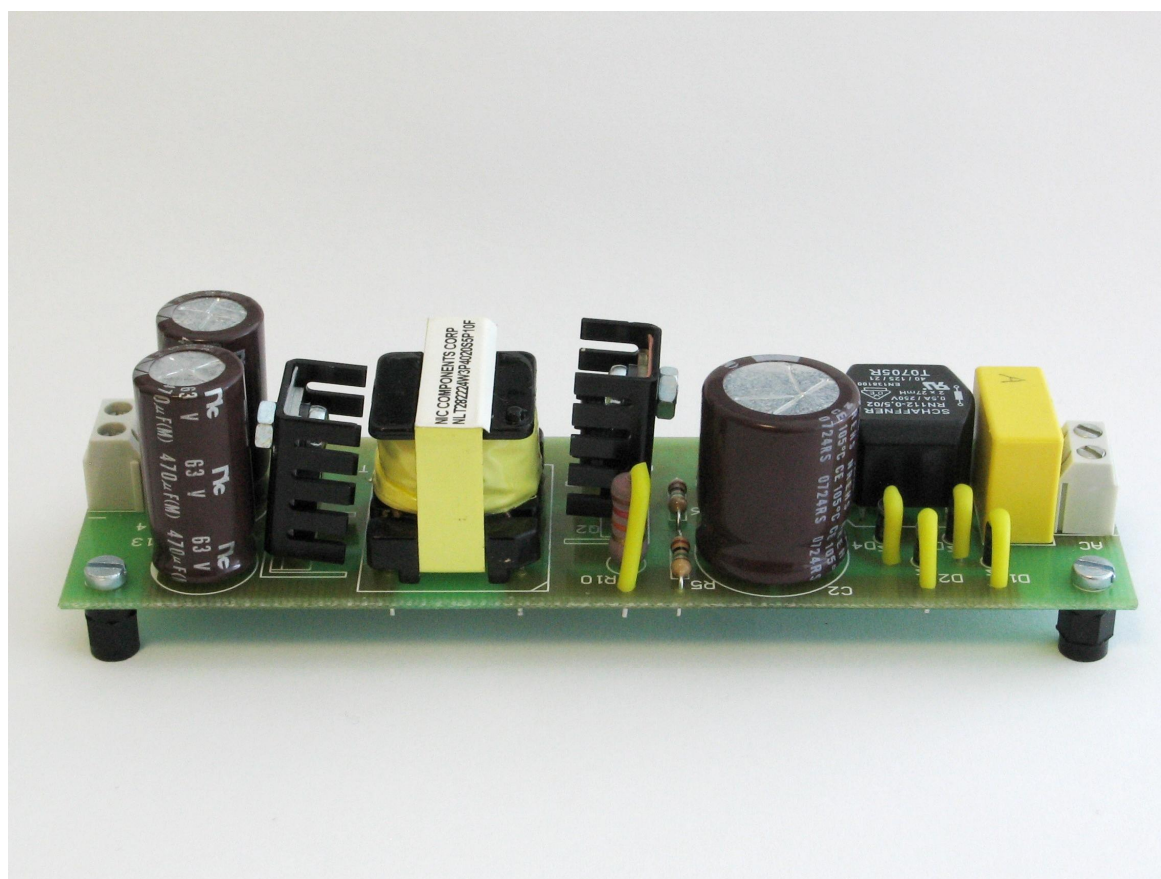
Drain waveform at 120 Vac and 230 Vac



Turn-off in detail at 120 Vac, 230 Vac and 265 Vac



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